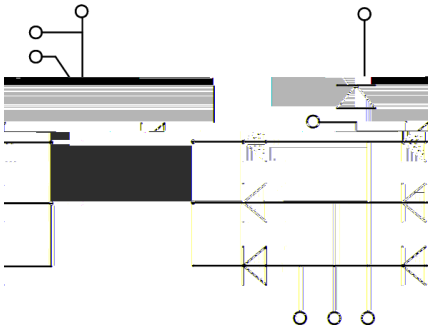
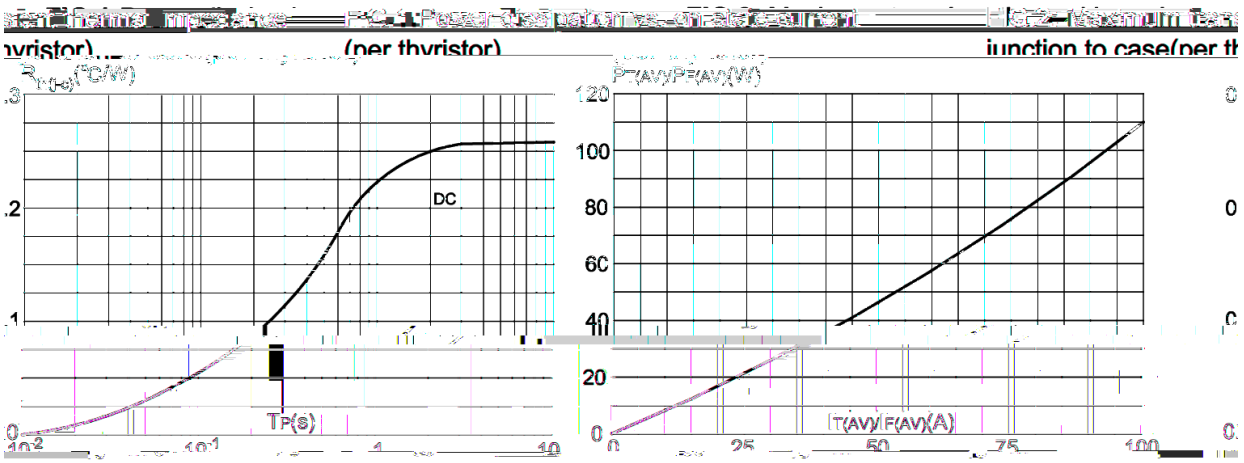


		D( )		
	℃			



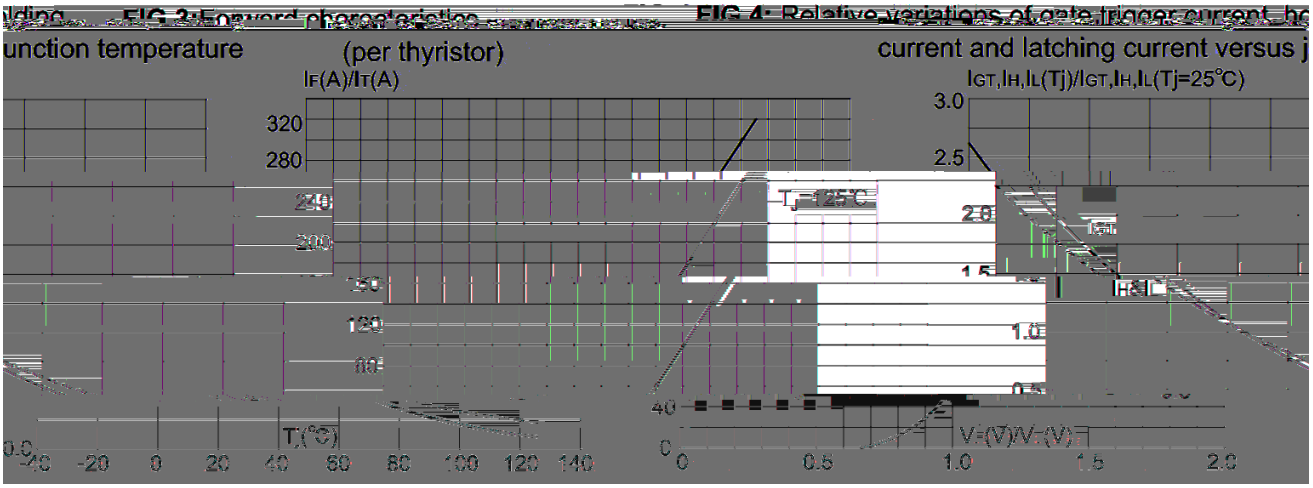


FIG.5 Gate trigger characteristics

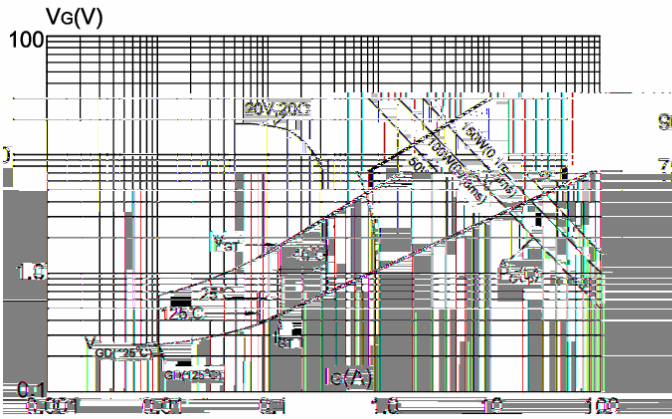


FIG.6: Forward current vs. case temperature (per thyristor)

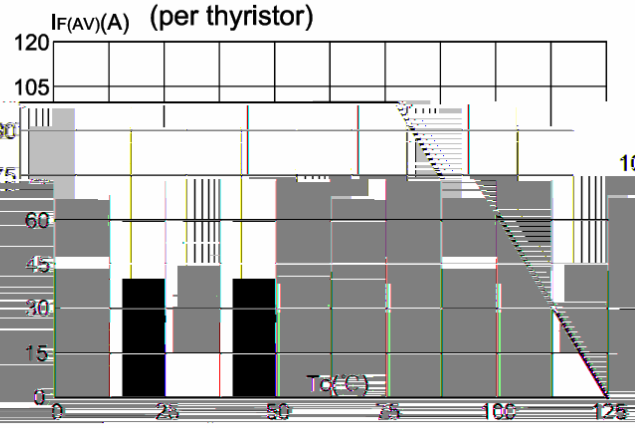


FIG.7: Forward characteristics(per diode)

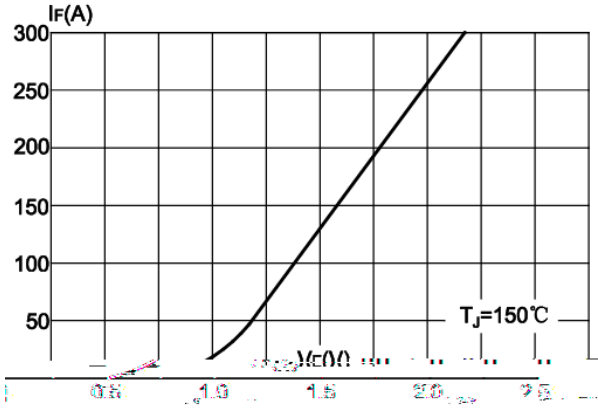
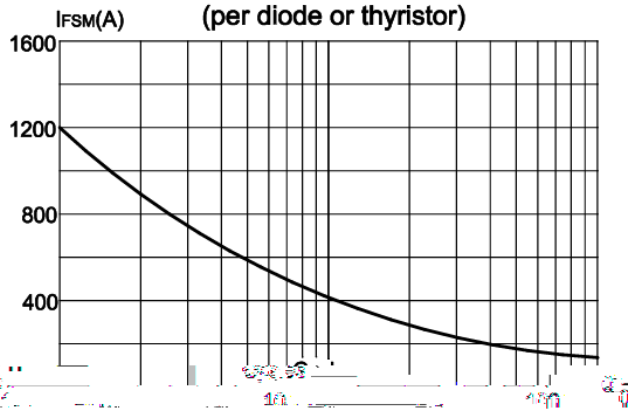


FIG.8: Peak on-state surge current (per diode or thyristor)



Maximum transient thermal impedance
/W) Junction-to-case(per diode)

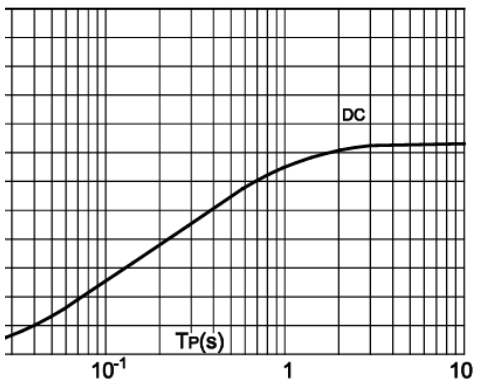


FIG.9: Forward current vs. case temperature (per diode)

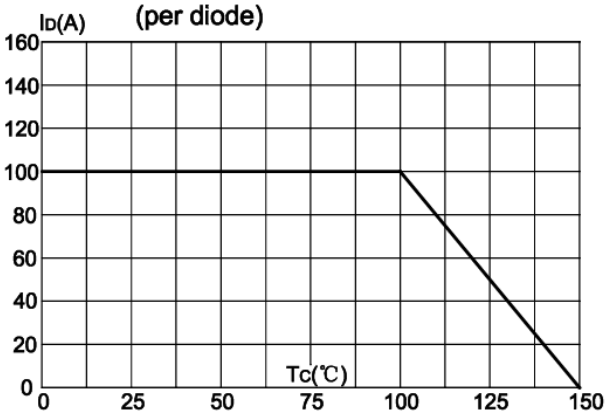
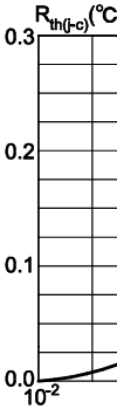
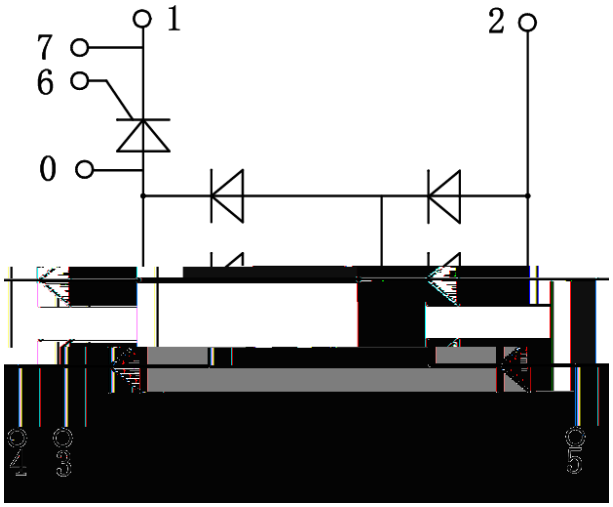
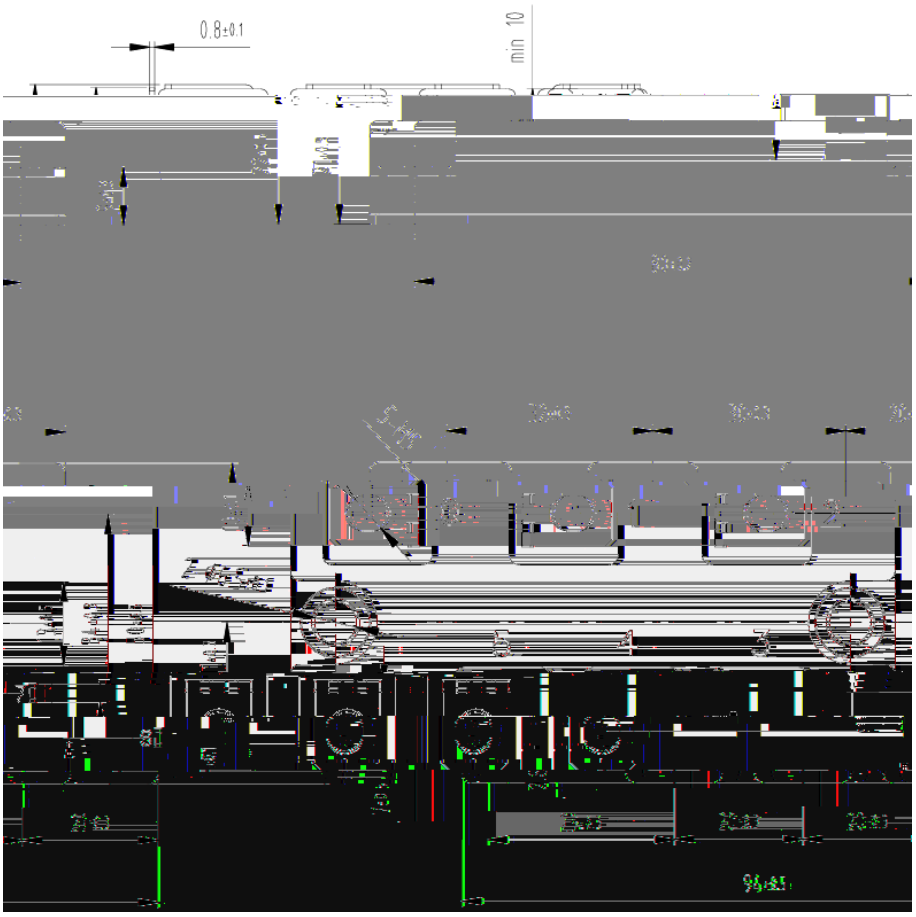


FIG.10:




1
2
7
6
0


0.8±0.1
min 10